

Wide Band Low Noise Amplifier 1.3GHz-2.9GHz



Product Description

R13M02GSA is a wideband low noise amplifier with a frequency range of 1.3 to 2.9GHz.

The power output of this amplifier is 25dBm typical. The typical gain is 30dB with a flatness of $\pm 0.5 \text{dB}.$

The working temperature of this product is between - 40°C and + 85°C.

Features

- Wide Band Low Noise Amplifier
- Gain 30dB Typical
- P1dB Output Power 25dBm Typical
- Supply Voltage +5V
- 50 Ohm Matched Input/Output
- Noise Figure +1.0dB Typical
- Gain Flatness +/-0.5dB

Typical Applications

- Wireless Infrastructure
- Military and Aerospace Applications
- Test Instrumentation
- Radar Systems
- 5G Wireless Communications
- Microwave Radio Systems
- TR Modules
 Besearch and [
- Research and Development
- Cellular Base Stations

Electrical Specifications (T_A=+25°C)

Pa	rameter	Min	Тур	Max	Min	Тур	Max	Units
Frequency Range		1.3		2.2	2.2		2.9	GHz
Gain		28	34		24	26		dB
Gain Flatness			±2	±2.5		±1.5	±2.0	dB
Gain Variation Over Temperature (-40ºC~+85ºC)			±0.5			±0.5		dB
Noise Figure			1.0	1.5		1.2	1.8	dB
Input VSWR			1.5	2.0		1.8	2.2	: 1
Output VSWR			1.8	2.0		1.8	2.2	: 1
Output Power for 1 dB Compression (P1dB)		22	25		23	25		dBm
Saturated Output Power (Psat)			26			26		dBm
Output Third Order Intercept (OIP3)			36			39		dBm
Supply Current (Vdd= 5V)			150	220		150	220	mA
Isolation S12			-50			-45		dB
\\/sinht	Net	0.04Max.						
Weight	Including Heat Sink	0.16Max.				- IDS.		
Impedance			50				Ohms	
Input / Output Connectors		SMA-Female (Input) – SMA-Female (Output)						
Package		Epoxy Sealed (Standard)						
		Hermetically Sealed (Optional)						



Absolute Maximum Ratings

Parameter	Rating
Operating Voltage	+6V
*RF Input Power (RFIN)	+25dBm

Bias Up Procedure

Bias Down Procedure

1. Connect ground

2. Connect input and output with 50 Ohm source/load. (In band VSWR < 1.9:1 or >10dB return loss.)

3. Connect positive supply and make sure power supply can handle max current.

1. Turn off power supply and remove positive supply

2. Disconnect input and output with 50 Ohm source/load. (In band VSWR < 1.9:1 or >10dB return loss.)

R13M02GSA

3. Remove ground

Environmental Specifications and Test Standards

Parameter	Description	
Operational Temperature	-40°C to +85°C (Case Temperature)	
Storage Temperature	-50°C to +105°C	
Thermal Shock	-40°C → +85°C (5 Cycles / 10 hours)	
**Random Vibration	MIL-STD-202G Table 214-I, Test Condition Letter C 1.5 Hours Per Axis	
High Temperature Burn In	Temperature +85°C for 72 Hours	
Shock	 Weight >20g, 50g half sine wave for 11ms, Speed variation 3.44m/s Weight <=20g, 100g Half sine wave for 6ms, Speed variation 3.75m/s Total 18 times (6 directions, 3 repetitions per direction). 	
Altitude	Standard: 30,000 Ft (Epoxy Sealed Controlled Environment) Optional: Hermetically Sealed (60,000 ft. 1.0 PSI min)	
Hermetically Sealed (Optional)	MIL-STD-883 (For Hermetically Sealed Units)	

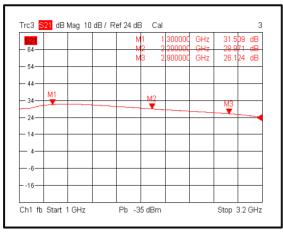
*Maximum RF input power is set to assure safety of amplifier. Input power may be increased at own risk to achieve full power of amplifier. Please reference gain and power curves.

**For vibration testing details please see additional information section.

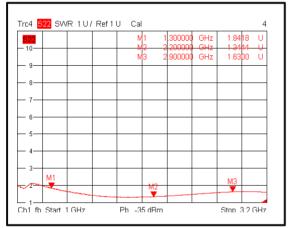


Typical Performance Plots

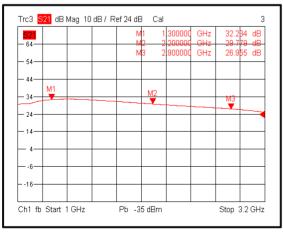
Gain@+25°C



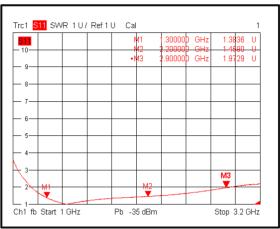
Output VSWR@+25°C



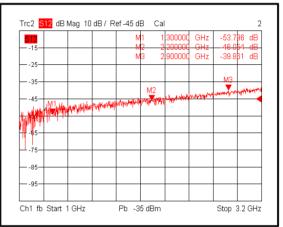
Gain@-40°C

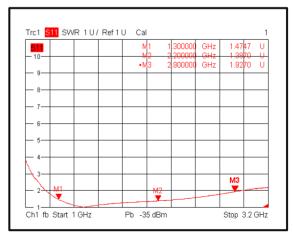


Input VSWR@+25°C



Isolation@+25°C





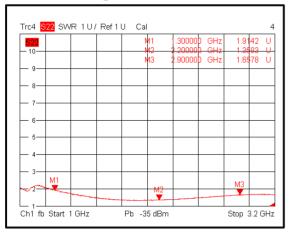
Input VSWR@-40°C



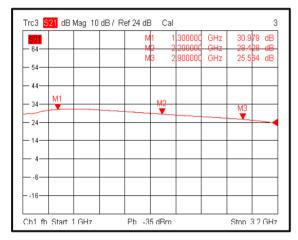
Typical Performance Plots

R13M02GSA

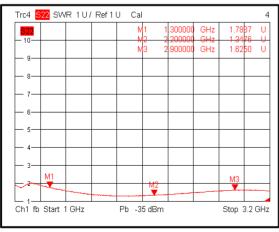
Output VSWR @-40°C



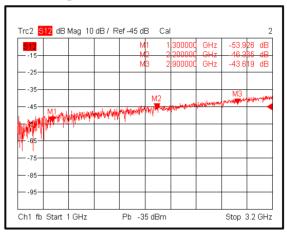
Gain@+85°C



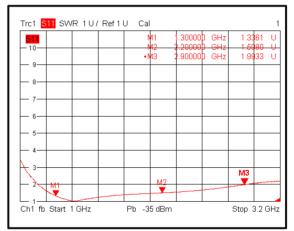
Output VSWR@+85°C



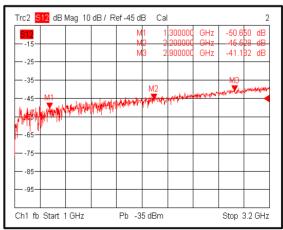
Isolation@-40°C



Input VSWR@+85°C



Isolation@+85°C

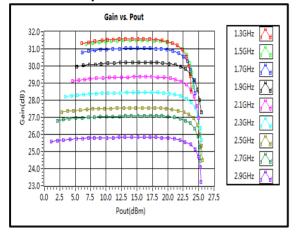




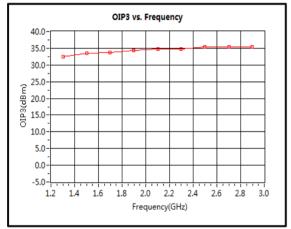
Typical Performance Plots

R13M02GSA

Gain vs. Output Power



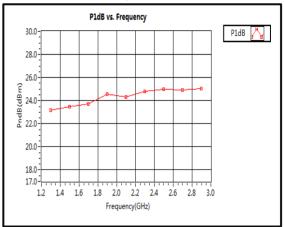
Output Third Order Intercept (OIP3)



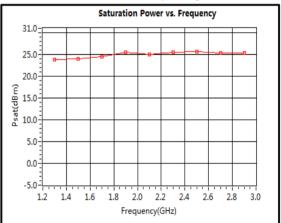
Noise Figure



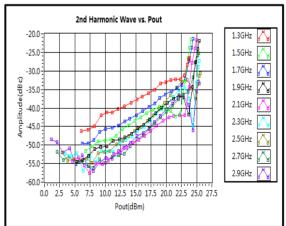
P1dB vs. Frequency



Saturation Power vs. Frequency



2nd Harmonic Wave Output Power

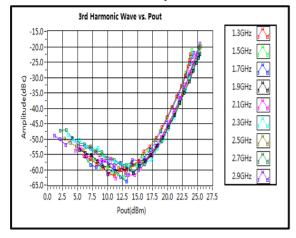




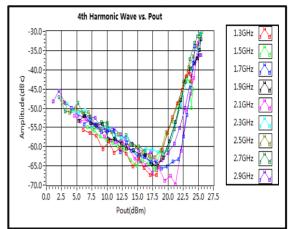
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Typical Performance Plots

3rd Harmonic Wave Output Power

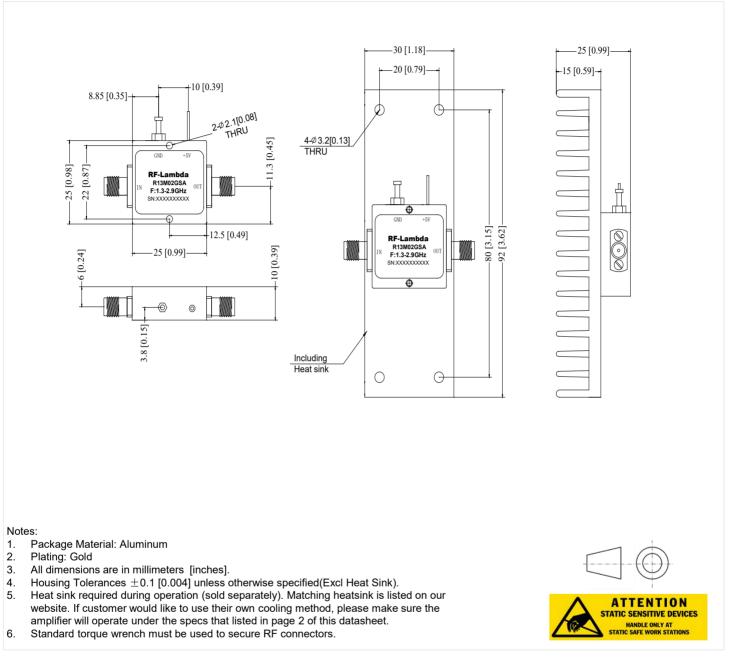


4th Harmonic Wave Output Power





Outline Drawing



Additional Information

Documentation	Webpage		
ESD Policy	https://rflambda.com/pdf/rflambda_esd_control.pdf		
Heatsink Lookup Specifications	https://rflambda.com/search_heatsink.jsp		
Connector Torque Specifications	https://www.rflambda.com/pdf/Torque_Specifications.pdf		
Random Vibration Test Standard	https://www.rflambda.com/pdf/rflambda_random_vibration_MIL-STD-202G.pdf		

R13M02GSA



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Ordering Information

Part Number	Modification	Description
R13M02GSA	Standard	1.3-2.9GHz Low Noise Amplifier

Amplifier Use

Ensure that the amplifier input and output ports are safely terminated into a proper 50 ohm load before turning on the power. Never operate the amplifier without a load. A proper 50 ohm load is defined as a load with impedance less than 1.9:1 or return loss larger than 10dB relative to 50 Ohm within the specified operating band width.

Power Supply Requirements

Power supply must be able to provide adequate current for the amplifier. Power supply should be able to provide 1.5 times the typical current or 1.2 times the maximum current (whichever is greater).

In most cases, RF - Lambda amplifiers will withstand severe mismatches without damage. However, operation with poor loads is discouraged. If prolonged operation with poor or unknown loads is expected, an external device such as an isolator or circulator should be used to protect the amplifier.

Ensure that the power is off when connecting or disconnecting the input or output of the amp.

Prevent overdriving the amplifier. Do not exceed the recommended input power level.

Adequate heat-sinking required for RF amplifier modules. Please inquire.

Amplifiers do not contain Thermal protection, Reverse DC polarity or Over voltage protection with the exception of a few models. Please inquire.

Proper electrostatic discharge (ESD) precautions are recommended to avoid performance degradation or loss of functionality.

What is not covered with warranty?

Each RF - Lambda amplifier will go through power and temperature stress testing. Since the die, ICs or MMICs are fragile, these are not covered by warranty. Any damage to these will NOT be free to repair.

Important Notice

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